PHOTONIC Silicon Photodiode, U.V. Enhanced Photoconductive DETECTORS INC. Type PDU-C113



PACKAGE DIMENSIONS INCH (mm) RED DOT INDICATES ANODE 0.140 [3.56] MAX 0.070 [1.78] 0.224 [5.69] 1.50 [38.1] MIN WIRE ANODE BONDS PHOTODIODE 120° Ø0.265 [6.73 VIEWING 0.200 [5.08] ANGLE G Ø0.020 [0.51] OPTICAL EPOXY CATHODE CERAMIC 0.125 [3.18] SQUARE CERAMIC PACKAGE 0.113 [2.87] SQ ACTIVE AREA

ACTIVE AREA = 7.95 mm^2

APPLICATIONS

- U.V. exposure meter
- Water purification
- Fluorescence
- U.V. A & B meters

with a clear U.V. transmitting epoxy glob top.

ABSOLUTE MAXIMUM RATING (TA=25°C unless otherwise noted)							
SYMBOL	PARAMETER MIN		MAX	UNITS			
VBR	Reverse Voltage		30	V			
T _{STG}	Storage Temperature	-40	+100	с			
To	Operating Temperature Range	-40	+90	°C			
Ts	Soldering Temperature*		+240	°C			
Ι	Light Current		500	mA			

DESCRIPTION

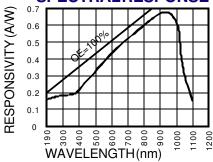
The PDU-C113 is a silicon, PIN planar

diffused, U.V. enhanced photodiode. Ideal

Packaged on a two lead ceramic substrate

for high speed photoconductive applications.

SPECTRALRESPONSE



*1/16 inch from case for 3 secs max

FEATURES

High speed

Low capacitance

• U.V. enhanced

Low dark current

ELECTRO-OPTICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

SYMBOL	CHARACTERISTIC	TESTCONDITIONS	MIN	TYP	MAX	UNITS				
lsc	Short Circuit Current	H = 100 fc, 2850 K	90	110		μA				
ΙD	Dark Current	$H = 0, V_{R} = 5 V$		10	50	nA				
Rsh	Shunt Resistance	$H = 0, V_{R} = 10 \text{ mV}$	100	250		MΩ				
TC RSH	RsH Temp. Coefficient	H = 0, V _R = 10 mV		-8		% / °C				
CJ	Junction Capacitance	$H = 0, V_{R} = 5 V^{**}$		130		рF				
λrange	Spectral Application Range	Spot Scan	250		1100	nm				
R	Responsivity	$V_R = 0 V, \lambda = 254 nm$.12	.18		A/W				
VBR	Breakdown Voltage	I = 10 µµA	15	25		V				
NEP	Noise Equivalent Power	V _R = 5 V @ Peak		2.2x10 ⁻¹⁴		W/\sqrt{Hz}				
tr	Response Time	$RL = 1 K\Omega V_R = 5 V$		58		nS				

Information in this technical data sheet is believed to be correct and reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice.**f=1 MHz [FORM NO. 100-PDU-C113 REV A]